



### **Product Summary**

•	Continuous Drain Source Voltage	$V_{DS} = 60V$
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- On-State Resistance 200mΩ
- Nominal Load Current (V<sub>IN</sub> = 5V) 2A
- Clamping Energy 480mJ

### Description

The ZXMS6005SG is a self protected low side IntelliFET<sup>TM</sup> MOSFET with logic level input. It integrates over-temperature; over-current, over-voltage (active clamp) and ESD protected logic level functionality. The ZXMS6005SG is ideal as a general purpose switch driven from 3.3V or 5V microcontrollers in harsh environments where standard MOSFETs are not rugged enough.

## Applications

- Especially Suited for Loads with a High In-rush Current such as Lamps and Motors
- All Types of Resistive, Inductive and Capacitive Loads in Switching Applications
- µC Compatible Power Switch for 12V DC Applications
- Automotive Rated
- Replaces Electromechanical Relays and Discrete Circuits
- Linear Mode capability the current-limiting protection circuitry is designed to de-activate at low V<sub>DS</sub> to minimize on state power dissipation. The maximum DC operating current is therefore determined by the thermal capability of the package/board combination, rather than by the protection circuitry. This does not compromise the product's ability to self-protect at low V<sub>DS</sub>.

#### **Features and Benefits**

- Compact High Power Dissipation Package
- Low Input Current
- Logic Level Input (3.3V and 5V)
- Short Circuit Protection with Auto Restart
- Over Voltage Protection (Active Clamp)
- Thermal Shutdown with Auto Restart
- Over-Current Protection
- Input Protection (ESD)
- High Continuous Current Rating
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative.

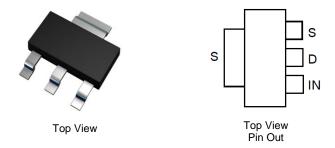
https://www.diodes.com/guality/product-definitions/

 An Automotive-Compliant Part is Available Under Separate Datasheet (ZXMS6005SGQ)

### **Mechanical Data**

- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound.
  UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish (e3)
- Weight: 0.112 grams (Approximate)

#### SOT223 (Type DN)



#### Ordering Information (Note 4)

Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
ZXMS6005SGTA	ZXMS6005S	7	12	1,000 Units
ZXMS6005SG-13	ZXMS6005S	13	12	2,500 Units

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

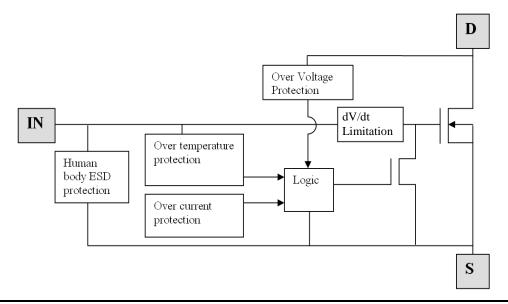
### **Marking Information**



 $\begin{array}{l} \text{ZXMS6005S} = \text{Product Type Marking Code} \\ \text{YWW} = \text{Date Code Marking} \\ \text{Y or } \overline{\text{Y}} = \text{Last Digit of Year (ex: 0 = 2020)} \\ \text{WW or } \overline{\text{WW}} = \text{Week Code (01 to 53)} \end{array}$ 



# **Functional Block Diagram**



# Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise stated.)

Characteristic	Symbol	Value	Unit
Continuous Drain-Source Voltage	Vds	60	V
Drain-Source Voltage for Short Circuit Protection	VDS(SC)	24	V
Continuous Input Voltage	V <sub>IN</sub>	-0.5 to +6	V
Continuous Input Current @-0.2V $\leq$ V <sub>IN</sub> $\leq$ 6V Continuous Input Current @V <sub>IN</sub> $<$ -0.2V or V <sub>IN</sub> $>$ 6V	lin	No limit   I <sub>IN</sub>   ≤2	mA
Pulsed Drain Current @VIN = 3.3V	Ідм	5	А
Pulsed Drain Current @V <sub>IN</sub> = 5V	Ідм	6	А
Continuous Source Current (Body Diode) (Note 5)	Is	2.5	А
Pulsed Source Current (Body Diode)	lsм	10	А
Unclamped Single Pulse Inductive Energy, T <sub>J</sub> = +25°C, $I_D$ = 0.5A, $V_{DD}$ = 24V	Eas	480	mJ
Electrostatic Discharge (Human Body Model)	Vesd	4000	V
Charged Device Model	V <sub>CDM</sub>	1000	V

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise stated.)

Characteristic	Symbol	Value	Unit
Power Dissipation at $T_A = +25^{\circ}C$ (Note 5) Linear Derating Factor	PD	1.0 8.0	W mW/°C
Power Dissipation at $T_A = +25^{\circ}C$ (Note 6) Linear Derating Factor	PD	1.6 12.8	W mW/°C
Thermal Resistance, Junction to Ambient (Note 5)	Reja	125	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	Reja	83	°C/W
Thermal Resistance, Junction to Case (Note 7)	Rejc	39	°C/W
Operating Temperature Range	TJ	-40 to +150	°C
Storage Temperature Range	Tstg	-55 to +150	°C

Notes: 5. For a device surface mounted on 15mm x 15mm single sided 1oz weight copper on 1.6mm FR-4 board, in still air conditions. Sink split drain 80% and source 20% to isolate connections.

6. For a device surface mounted on 50mm x 50mm single sided 2oz weight copper on 1.6mm FR-4 board, in still air conditions. Sink split drain 80% and source 20% to isolate connections.

7. Thermal resistance between junction and the mounting surfaces of drain and source pins.

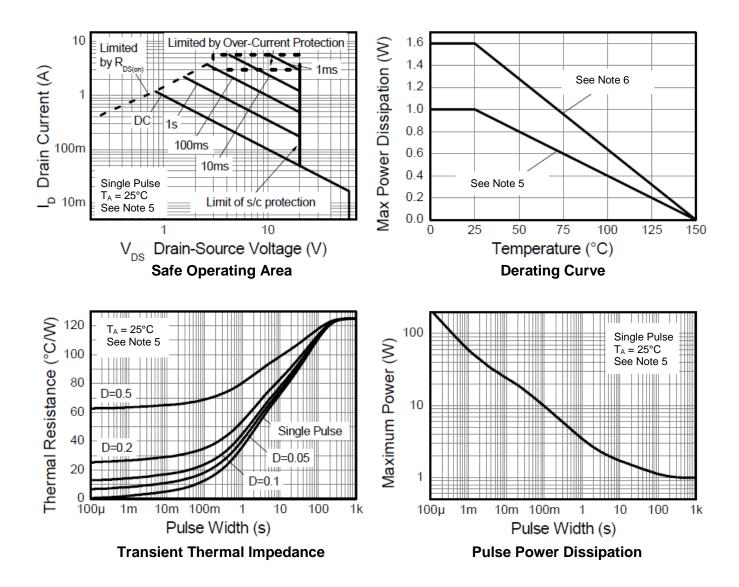


# **Recommended Operating Conditions**

The ZXMS6005SG is optimized for use with  $\mu$ C operating from 3.3V and 5V supplies.

Characteristic	Symbol	Min	Max	Unit
Input Voltage Range	Vin	0	5.5	V
Ambient Temperature Range	T <sub>A</sub>	-40	+125	°C
High Level Input Voltage for MOSFET to Be On	VIH	3	5.5	V
Low Level Input Voltage for MOSFET to Be Off	VIL	0	0.7	V
Peripheral Supply Voltage (Voltage to Which Load Is Referred)	VP	0	24	V

# **Thermal Characteristics**





#### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise stated.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Static Characteristics				•	•	
Drain-Source Clamp Voltage	VDS(AZ)	60	65	70	V	I <sub>D</sub> = 10mA
Off State Drain Correct		_	_	1		$V_{DS} = 12V, V_{IN} = 0V$
Off State Drain Current	I <sub>DSS</sub> — — 2	2	μA	$V_{DS} = 36V, V_{IN} = 0V$		
Input Threshold Voltage	VIN(TH)	0.7	1.2	1.5	V	$V_{DS} = V_{GS}, I_D = 1mA$
		_	60	100	۵	$V_{IN} = 3V$
Input Current	lin	_	120	200	μA	$V_{IN} = 5V$
Input Current While Over Temperature Active	—	_	_	300	μA	VIN = 5V
Statia Ducia Courses On State Desistance	5	_	170	250	mΩ	VIN = 3V, ID = 1A
Static Drain-Source On-State Resistance	RDS(ON)	_	150	200		V <sub>IN</sub> = 5V, I <sub>D</sub> = 1A
Continuous Drain Current (Note 5)		1.4	_	—	- A	VIN = 3V, T <sub>A</sub> = +25°C
Continuous Drain Current (Note 5)		1.6	_	—		VIN = 5V, TA = +25°C
Continuous Drain Current (Note 6)	ID	1.9	_	—		VIN = 3V, T <sub>A</sub> = +25°C
Continuous Drain Current (Note 6)		2.0	_	—		VIN = 5V, TA = +25°C
Current Limit (Note 9)	I <sub>D(LIM)</sub>	2.2	5	—	A	V <sub>IN</sub> = 3V
Current Limit (Note 8)		3.3	7	—		VIN = 5V
Dynamic Characteristics						
Turn On Delay Time	t <sub>D(ON)</sub>	_	6	—		
Rise Time	t <sub>R</sub>	_	14	—		$V_{DD} = 12V, I_D = 1A, V_{GS} = 5V$
Turn Off Delay Time	tD(OFF)	_	34	—	μs	
Fall Time	tF	_	19	_		
Over-Temperature Protection	·					-
Thermal Overload Trip Temperature (Note 9)	TJT	+150	+175	_	°C	—
Thermal Hysteresis (Note 9)	_		+10		°C	—

Notes: 5. For a device surface mounted on 15mm x 15mm single sided 1oz weight copper on 1.6mm FR-4 board, in still air conditions. Sink split drain 80% and source 20% to isolate connections.

6. For a device surface mounted on 50mm x 50mm single sided 2oz weight copper on 1.6mm FR-4 board, in still air conditions. Sink split drain 80% and source 20% to isolate connections.

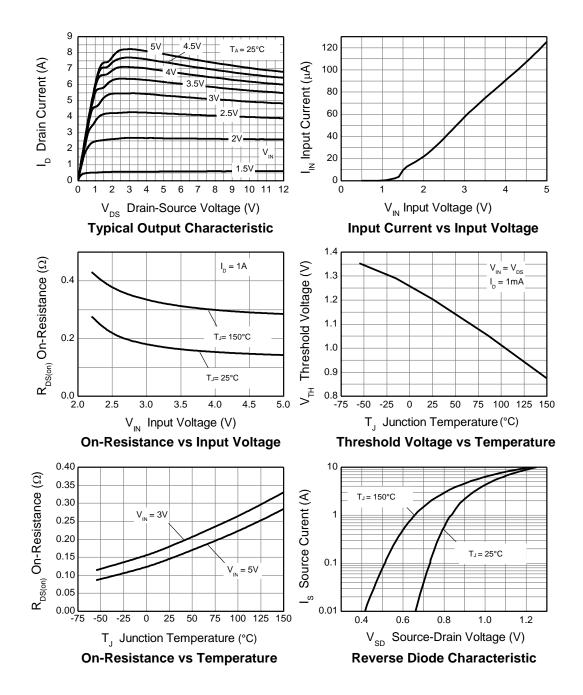
7. Thermal resistance between junction and the mounting surfaces of drain and source pins.

8. The drain current is restricted only when the device is in saturation (see graph 'Typical Output Characteristic'). This allows the device to be used in the fully on state without interference from the current limit. The device is fully protected at all drain currents, as the low power dissipation generated outside saturation makes current limit unnecessary.

9. Over-temperature protection is designed to prevent device destruction under fault conditions. Fault conditions are considered as "outside" normal operating range, so this part is not designed to withstand over-temperature for extended periods.

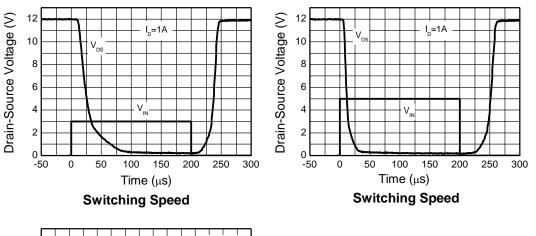


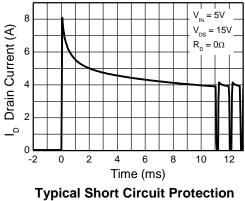
# **Typical Characteristics**





# Typical Characteristics (continued)



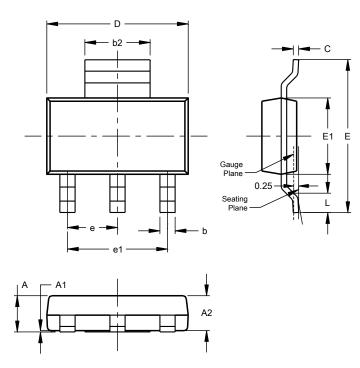




# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

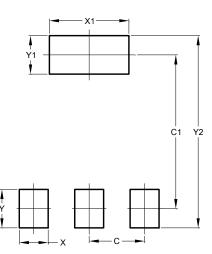
# SOT223 (Type DN)



SOT223 (Type DN)							
	IVIIN		Тур				
Α		1.70					
A1	0.01	0.15					
A2	1.50	1.68	1.60				
b	0.60	0.80	0.70				
b2	2.90	3.10					
С	0.20	0.32					
D	6.30	6.70					
Е	6.70	7.30					
E1	3.30	3.70					
е			2.30				
e1			4.60				
L	0.85						
All Dimensions in mm							

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



#### SOT223 (Type DN)

Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



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